



#### **40V P-CHANNEL ENHANCEMENT MODE MOSFET**

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C (Note 6)
-40V	$25m\Omega$ @ V <sub>GS</sub> = -10V	-8.6A
-40 V	45mΩ @ V <sub>GS</sub> = -4.5V	-7.0A

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor controls
- Backlighting
- DC-DC converters
- Printer equipment

### **Features**

- Low On-Resistance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP4025LK3Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

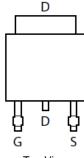
#### **Mechanical Data**

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.315 grams (Approximate)

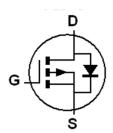




Top View



Top View Pin Out



Device Symbol

### Ordering Information (Note 4)

Part Number	Dookowa	Packing		
Part Number	Package	Qty.	Carrier	
DMP4025LK3Q-13	TO252 (DPAK)	2,500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# **Marking Information**



Oll = Manufacturer's Marking P4025L = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 23 = 2023) WW = Week (01 to 53)



# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage	Drain-Source Voltage			-40	V
Gate-Source Voltage		Vgss	±20		
		(Note 6)		-8.6	
Continuous Drain Current	Vgs = -10V	$T_A = +70^{\circ}C \text{ (Note 6)}$	lD	-6.9	
		(Note 5)		-6.7	
Pulsed Drain Current	V <sub>GS</sub> = -10V	(Note 7)	I <sub>DM</sub>	-40	Α
Continuous Source Current (Body Diode)		(Note 7)	Is	-8.6	
Pulsed Source Current (Body Diode) (Note 7)		(Note 7)	I <sub>SM</sub>	-40	

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Down Dissination	(Note 5)	D-	1.7	10/	
Power Dissipation	(Note 6)	P <sub>D</sub>	2.78	W	
Thermal Resistance, Junction to Ambient	(Note 5)		74		
	(Note 6)	Reja	45		
Thermal Resistance, Junction to Case	(Note 6)	Rejc	7.1	°C/W	
Thermal Resistance, Junction to Lead	(Note 8)	Rejl	1.43		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Notes:

- 5. For a device surface mounted on minimum recommended FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Same as note (5), except the device is surface mounted on 25mm X 25mm X 1.6mm FR4 PCB.

  7. Repetitive rating on 25mm X 25mm FR4 PCB, D=0.02, pulse width 300µs pulse width by maximum junction temperature.

  8. Thermal resistance from junction to solder-point (at the end of the drain lead).



### **Thermal Characteristics**

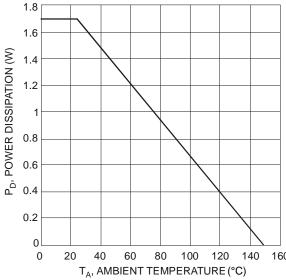


Figure 1. Power Dissipation vs. Ambient Temperature

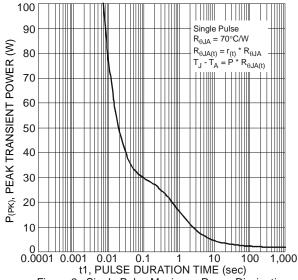
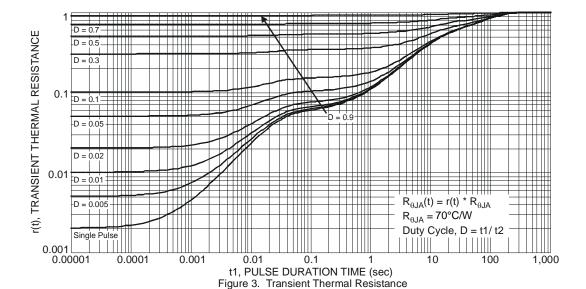


Figure 2. Single Pulse Maximum Power Dissipation





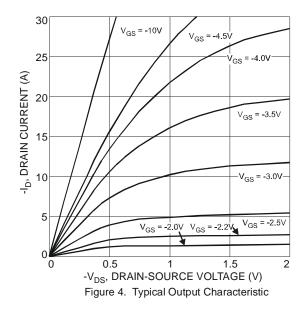
### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

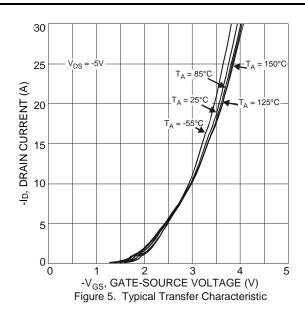
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BVDSS	-40	_	_	V	I <sub>D</sub> = -250µA, V <sub>G</sub> S = 0V	
Zero Gate Voltage Drain Current	IDSS		_	-1	μA	V <sub>DS</sub> = -40V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.8	-1.3	-1.8	V	$I_D = -250\mu A,\ V_{DS} = V_{GS}$	
Static Drain-Source On-Resistance (Note 9)	2		18	25	mΩ	$V_{GS} = -10V, I_{D} = -3A$	
Static Drain-Source On-Resistance (Note 9)	RDS(ON)	_	30	45	11177	VGS = -4.5V, ID = -3A	
Forward Transconductance (Notes 9 & 10)	<b>G</b> fs	_	16.6	_	S	V <sub>DS</sub> = -5V, I <sub>D</sub> = -3A	
Diode Forward Voltage (Note 9)	VsD	_	-0.7	-1	V	Is = -1A, VGS = 0V	
DYNAMIC CHARACTERISTICS (Note 10)			•	•			
Input Capacitance	Ciss	_	1643	_		V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V f = 1MHz	
Output Capacitance	Coss	_	179	_	pF		
Reverse Transfer Capacitance	Crss	_	128	_			
Gate Resistance	Rg	_	6.43	_	Ω	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 0V, f = 1MHz	
Total Gate Charge (Note 11)	Qg	_	14	_		Vgs = -4.5V	
Total Gate Charge (Note 11)	Qg	_	33.7	_		V <sub>DS</sub> = -20V	
Gate-Source Charge (Note 11)	Q <sub>gs</sub>		5.5	_	nC	$V_{GS} = -10V$ $I_D = -3A$	
Gate-Drain Charge (Note 11)	$Q_{gd}$	_	7.3	_			
Turn-On Delay Time (Note 11)	t <sub>D(ON)</sub>		6.9	_		·	
Turn-On Rise Time (Note 11)	t <sub>R</sub>	_	14.7	_	]	V <sub>DD</sub> = -20V, V <sub>GS</sub> = -10V	
Turn-Off Delay Time (Note 11)	t <sub>D(OFF)</sub>	_	53.7	_	ns	I <sub>D</sub> = -3A	
Turn-Off Fall Time (Note 11)	tF	_	30.9	_	]		

Notes:

- 9. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s;$  duty cycle  $\leq 2\%.$
- 10. For design aid only, not subject to production testing.
  11. Switching characteristics are independent of operating junction temperatures.

# **Typical Characteristics**



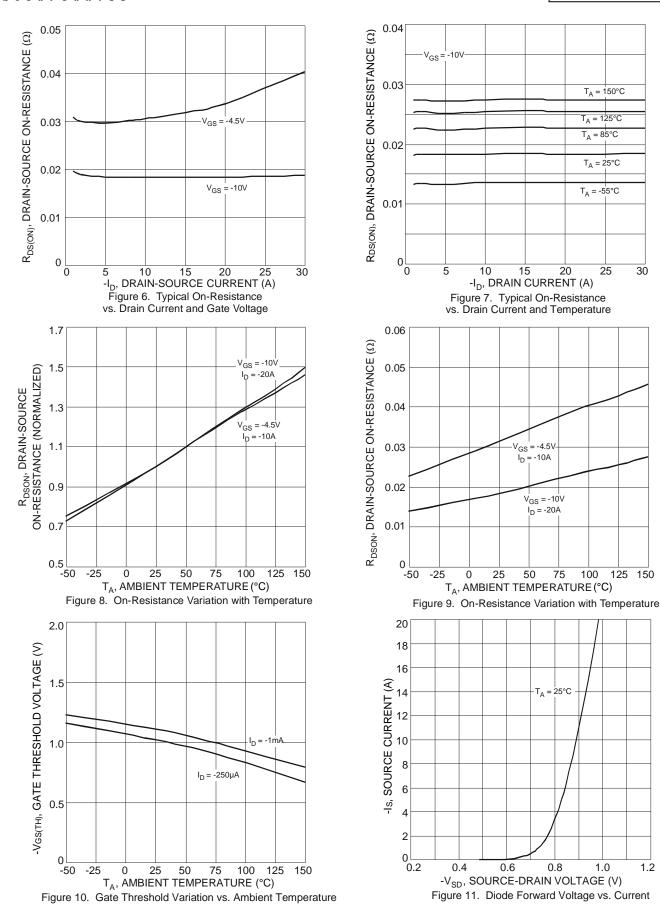


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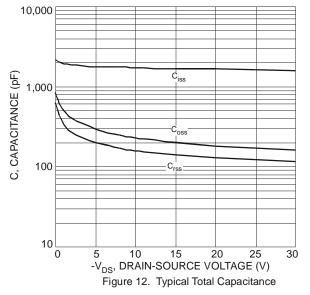
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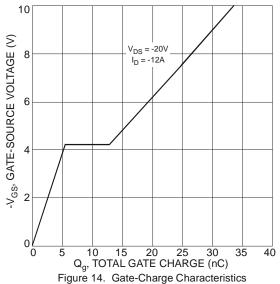
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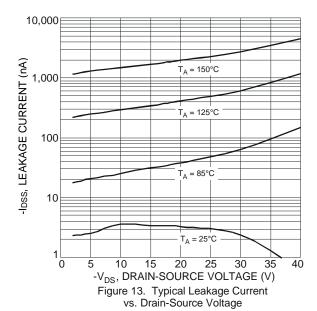


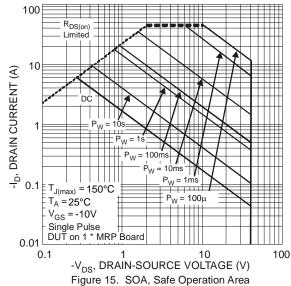










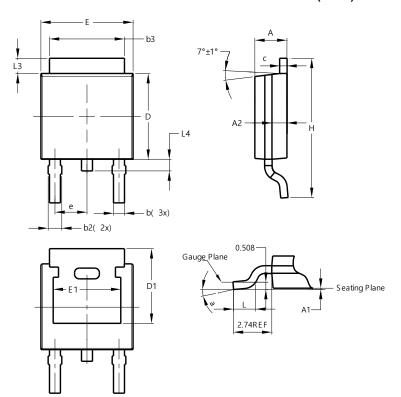




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### TO252 (DPAK)

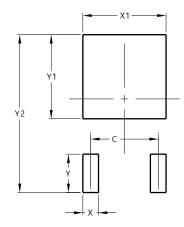


	TO252 (DPAK)				
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
<b>A1</b>	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.50	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21				
е	2.286 BSC				
Е	6.45	6.70	6.58		
E1	4.32				
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All	All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **TO252 (DPAK)**



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Y	2.600		
Y1	5.700		
Y2	10.700		



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